

HAC RF Emissions Test Report

Test report no.:	Salo_HAC_0913_02	Date of report:	2009-04-03
Template version:	5.1	Number of pages:	30
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Measurements made by:	Heikki Kuusela		
Tested devices:	RM-507 (Hearing aid mode active)		
FCC ID:	QVVRM-507	IC:	661AE-RM507
Supplement reports:	Salo_HAC_0913_03		
Testing has been carried out in accordance with:	ANSI C63.19-2007 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids		
Documentation:	The documentation of the testing performed on the tested devices is archived for 15 years at TCC Nokia.		
Test results:	The tested device complies with the requirements in respect of all parameters subject to the test. The test results and statements relate only to the items tested. The test report shall not be reproduced except in full, without written approval of the laboratory.		
Date and signatures:			
For the contents:			

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1. SUMMARY OF HAC RF EMISSION TEST REPORT

1.1 Test Details

Period of test	2009-03-23 to 2009-03-24
SN, HW, SW and DUT numbers of tested device	SN:004401/10/405349/7, HW: 2304, SW: 52.50.2009.08, DUT: 13613
Batteries used in testing	BP-4L, DUT: 13509, 13510, 13511, 13512, 13513, 13514
State of sample	Prototype unit
Notes	AWF = -5 for GSM, 0 for WCDMA

1.2 Maximum Results

The maximum measured HAC RF emissions values and categories for electric and magnetic fields are given in section 1.2.1 and 1.2.2 respectively.

1.2.1 Electric field measurements

Band & Mode	Ch / Freq. [MHz]	Radiated power	Limit of E-field max. value in category M3 [V/m]	Maximum E-field value after exclusion [V/m]	Category
GSM850	128 / 824.2	28.3 dBm ERP	149.6 – 266.1	164.3	M3 (-5dB)
WCDMA850	4175 / 835.0	18.4 dBm ERP	199.5 – 354.8	43.8	M4 (0dB)
GSM1900	661 / 1880.0	30.5 dBm EIRP	47.3 – 84.1	77.7	M3 (-5dB)
WCDMA1900	9262 / 1852.4	20.1 dBm EIRP	63.1 – 112.2	29.9	M4 (0dB)

1.2.2 Magnetic field measurements

Band & Mode	Ch / Freq. [MHz]	Radiated power	Limit of H-field max. value in category M3 [A/m]	Maximum H-field value after exclusion [A/m]	Category
GSM850	128 / 824.2	28.3 dBm ERP	0.45 – 0.80	0.28	M4 (-5dB)
WCDMA850	4132 / 826.4	17.9 dBm ERP	0.60 – 1.07	0.08	M4 (0dB)
GSM1900	661 / 1880.0	30.5 dBm EIRP	0.14 – 0.25	0.16	M3 (-5dB)
WCDMA1900	9262 / 1852.4	20.1 dBm EIRP	0.19 – 0.34	0.08	M4 (0dB)

1.2.3 Overall RF emissions category of the tested device

Band & Mode	Combined category (E- and H-fields)	Pass / Fail
GSM850	M3	Pass
WCDMA850	M4	Pass
GSM1900	M3	Pass
WCDMA1900	M4	Pass
Final Category	M3	Pass

1.2.4 Maximum Drift

Maximum drift during measurements	0.49 dB
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1.2.5 Measurement Uncertainty

Extended Uncertainty (k=2) 95%, E-field	14.7 %
Extended Uncertainty (k=2) 95%, H-field	10.9 %

2. DESCRIPTION OF THE DEVICE UNDER TEST (DUT)

Modes of Operation	Bands	Modulation Mode	Duty Cycle	Transmitter Frequency Range (MHz)
GSM	850	GMSK	1/8	824 – 849
GSM	1900	GMSK	1/8	1850 – 1910
WCDMA	850 (Band V)		1	826 – 847
WCDMA	1900 (Band II)		1	1852 - 1908

Outside of USA the transmitter of the device is capable of operating also in 900MHz, 1800MHz and 2100MHz bands, which are not part of this filing.

2.1 Picture of Device

See separate report 'Salo_HAC_0913_03'

3. TEST CONDITIONS

3.1 Temperature and Humidity

Ambient temperature [°C]:	19.9 to 21.9
Ambient humidity [RH %]:	31 to 34

3.2 Test Signal, Frequencies, and Output Power

The transmitter of the device was put into operation by using a call tester. Communications between the device and the call tester were established by air link.

For all tests the device output power was set to maximum power level; a fully charged battery was used for every test sequence.

The transmission mode of the device in WCDMA HAC RF emission tests was configured to 12.2kbps RMC with all TPC bits set as “1”.

The measurements were performed on low, middle and high channels.

The radiated output power of the device was measured by a separate test laboratory on the same unit(s) as used for HAC testing.

4. DESCRIPTION OF THE TEST EQUIPMENT

4.1 Measurement system and components

The measurements were performed using an automated near-field scanning system, DASY 4, manufactured by Schmid & Partner Engineering AG (SPEAG) in Switzerland.
The following table lists calibration dates of SPEAG components:

Test Equipment	Serial Number	Calibration interval	Calibration expiry
DAE 4	555	12 months	2009-11
E-field Probe ER3DV6	2309	12 months	2009-11
H-field Probe H3DV6	6143	12 months	2009-11
Dipole Validation Kit, CD835V3	1005	24 months	2010-11
Dipole Validation Kit, CD1880V3	1004	24 months	2010-11
DASY4 software	Version 4.7	-	-

Additional test equipment used in testing and validation:

Test Equipment	Model	Serial Number	Calibration interval	Calibration expiry
Signal Generator	SML03	101265	12 months	2009-07
Amplifier	ZHL-42 (SMA)	N072095-5	12 months	2009-07
Power Meter	NRVS	849305/028	12 months	2009-07
Power Sensor	NRV-Z32	839176/020	12 months	2009-07
Call Tester	CMU 200	101111	-	-

4.1.1 Isotropic E-field probe ER3DV6

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Frequency	In air 100 MHz to >6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm Tip length: 16 mm Body diameter: 12 mm Tip diameter: 8 mm
Application	Distance from probe tip to nearest point of dipole: 1.25 mm General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

4.1.2 Isotropic H-field probe H3DV6

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material
Frequency	200 MHz to 3 GHz; Output linearized (absolute accuracy $\pm 6.0\%$, $k=2$)
Directivity	± 0.25 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
Dimensions	Overall length: 330 mm Tip length: 40 mm Body diameter: 12 mm Tip diameter: 6 mm
Application	Distance from probe tip to nearest point of dipole: 1.1 mm General magnetic near-field measurements up to 3 GHz Field component measurements, surface current measurements Measurements in air or liquids, low interaction

4.1.3 Device Holder

The Device Holder and Test Arch are manufactured by Speag (<http://www.dasy4.com/hac>). Test arch is used for all tests i.e. for both validation testing and device testing. The holder and test arch conforms to the requirements of ANSI C63.19.

The SPEAG device holder (see Section 5.1) was used to position the test device in all tests.

4.2 Validation of the System

The manufacturer calibrates the probes annually. Validation measurements are made regularly using the dipole validation kit. The power level used by manufacturer in dipole calibration is supplied to the dipole antenna. The antenna is scanned at 1.0cm distance between top surface of the dipole and calibration point of the probe.

System Validation, H-field and E-field

f [MHz]	Description	E-field [V/m]	H-field [A/m]
835	Reference result	164.1	0.441
	$\pm 10\%$ window	147.7 – 180.5	0.397 – 0.485
	2009-03-23	-	0.456
	2009-03-24	163.2	-
1880	Reference result	137.9	0.461
	$\pm 10\%$ window	124.1 – 151.7	0.415 – 0.507
	2009-03-23	-	0.465
	2009-03-24	138.7	-

Plots of the system validation scans are given in Appendix A.

5. DESCRIPTION OF THE TEST PROCEDURE

5.1 Test Arch and Device Holder

The test device was placed in the Device Holder (illustrated below) that is supplied by SPEAG. Using this positioner the tested device is positioned under Test Arch.



Device holder and Test Arch supplied by SPEAG

5.2 Test Positions

5.2.1 Scan area centered at the acoustic output

The device was positioned such that Device Reference plane was touching the bottom of the Test Arch. The scan is centered at the acoustic output by aligning the acoustic output with the intersection of the Test Arch's middle bar and dielectric wire.

5.3 Scan Procedures

Near field scans of 5cm x 5cm were used for determination of the field distribution. Measurement plane distance from WD reference plane is 1cm. Scans were performed for both E- and H-field using appropriate probe. DASY software divides detected values into 3 x 3 sub grids as described in the C63.19 standard.

5.4 Scan area centered at the maximum magnetic T-coil coupling

Scanning centered at the maximum magnetic T-coil coupling was not applicable for the tested device.

5.5 Probe Modulation Factor

All raw measurements in DASY4 system are presented as RMS values. The measurement software then applies Probe Modulation Factor (PMF) to convert readings to “slot averaged” peak values as required by C63.19 standard.

Therefore PMF was assessed as described in C63.19 standard along with Speag's Application Note (AN_Hearing_Aid_Compatibility.pdf, section 28.8, "Definition / Determination of the Probe Modulation Factor").

Observed Modulation Factor:

$$PMF_{(E)} = E\text{-field}_{(CW)} / E\text{-field}_{(Modulated)}$$

$$PMF_{(H)} = H\text{-field}_{(CW)} / H\text{-field}_{(Modulated)}$$

Observed Crest Factor:

$$CF_{(E)} = (PMF_{(E)})^2$$

$$CF_{(H)} = (PMF_{(H)})^2$$

Modulation factors, GSM

f [MHz]	P_{max} [dBm]	E-field [V/m] Probe SN: 2309		H-field [A/m] Probe SN: 6143		PMF E-field	PMF H-field
		CW	GSM	CW	GSM		
835.0	20	107.4	38.2	0.503	0.186	2.81	2.70
1880.0	20	161.4	56.9	0.519	0.232	2.84	2.24

Modulation factors, WCDMA

f [MHz]	P_{max} [dBm]	E-field [V/m] Probe SN: 2309		H-field [A/m] Probe SN: 6143		PMF E-field	PMF H-field
		CW	WCDMA	CW	WCDMA		
835.0	17	32.6	41.5	0.154	0.201	0.79	0.77
1880.0	17	44.3	59.0	0.161	0.226	0.75	0.71

5.6 Slot Averaged Calculation Method

The slot-averaged values for the every measured signal type were calculated using observed duty cycles.

5.7 Sub-grid Exclusion

The measurement grid defined in C63.19 consists of 9 evenly sized blocks, which are used to define permissible exclusion areas. For both E- and H-field measurements three contiguous blocks may be excluded from the measurements except center block may never be excluded. There must be 4 blocks left that are common for both E- and H-field measurements, so maximum of 5 different blocks can be excluded (e.g. 3 blocks excluded from E-field and 2 blocks from H-field).

5.8 Category Limits

From remaining maximum values after exclusion process, Hearing Aid M-category is defined according to the category limits of C63.19 – 2007.

		Limits for RF-parameters <960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	631.0 to 1122.0	1.91 to 3.39
	-5	473.2 to 841.4	1.43 to 2.54
M2	0	354.8 to 631.0	1.07 to 1.91
	-5	266.1 to 473.2	0.80 to 1.43
M3	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M4	0	<199.5	<0.60
	-5	<149.6	<0.45

		Limits for RF-parameters >960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M2	0	112.2 to 199.5	0.34 to 0.60
	-5	84.1 to 149.6	0.25 to 0.45
M3	0	63.1 to 112.2	0.19 to 0.34
	-5	47.3 to 84.1	0.14 to 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

6. MEASUREMENT UNCERTAINTY

Source of Uncertainty	Tolerance ±%	Probability Distribution	Div.	ci E	ci H	Standard Uncertainty ±%, E	Standard Uncertainty ±%, H	Remark
MEASUREMENT SYSTEM								
Probe Calibration	5.1	N	1	1	1	5.1	5.1	
Axial Isotropy	4.7	R	√3	1	1	2.7	2.7	
Sensor Displacement	16.5	R	√3	1	0.145	9.5	1.4	
Boundary Effect	2.4	R	√3	1	1	1.4	1.4	
Linearity	4.7	R	√3	1	1	2.7	2.7	SAR
Scaling to Peak Envelope Power	2.0	R	√3	1	1	1.2	1.2	
System Detection Limit	1.0	R	√3	1	1	0.6	0.6	
Readout Electronics	0.3	N	1	1	1	0.3	0.3	SAR
Response Time	0.8	R	√3	1	1	0.5	0.5	
Integration Time	2.6	R	√3	1	1	1.5	1.5	SAR
RF Ambient Conditions	3.0	R	√3	1	1	1.7	1.7	SAR
RF Reflections	12.0	R	√3	1	1	6.9	6.9	
Probe Positioner	1.2	R	√3	1	0.67	0.7	0.5	
Probe Positioning	4.7	R	√3	1	0.67	2.7	1.8	
Extrapolation and Interpolation	1.0	R	√3	1	1	0.6	0.6	SAR
TEST SAMPLE RELATED								
Device Positioning Vertical	4.7	R	√3	1	0.67	2.7	1.8	
Device Positioning Lateral	1.0	R	√3	1	1	0.6	0.6	
Device Holder and Test Arch	2.4	R	√3	1	1	1.4	1.4	
Power Drift	5.0	R	√3	1	1	2.9	2.9	SAR
TEST ARCH AND SETUP RELATED								
Test Arch Thickness	2.4	R	√3	1	0.67	1.4	0.9	
COMBINED STANDARD UNCERTAINTY						14.7	10.9	
Expanded Uncertainty on Power						29.4	21.8	
Expanded Uncertainty on Field						14.7	10.9	

7. RESULTS

The calculated maximum field values for the test device are tabulated below:

850 MHz, E and H RF emissions results

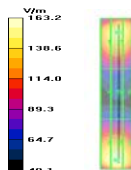
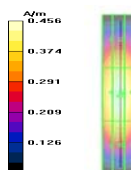
Mode	Option	Test configuration	Ch 128 824.2MHz	Ch 190 836.6MHz	Ch 251 848.8MHz
GSM	Phone Slide Closed	Power	28.3 dBm	27.9 dBm	27.8 dBm
		E-field [V/M]	164.3	155.2	129.7
		H-field [A/m]	0.283	0.251	0.207
		Category	M3 (-5 dB)	M3 (-5 dB)	M4 (-5 dB)
Mode	Option	Test configuration	Ch 4132 826.4MHz	Ch 4175 835.0MHz	Ch 4233 846.6MHz
WCDMA	Phone Slide Closed	Power	17.9 dBm	18.4 dBm	18.1 dBm
		E-field [V/M]	43.6	43.8	38.0
		H-field [A/m]	0.075	0.072	0.063
		Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

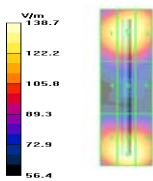
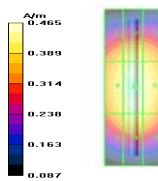
1900 MHz, E and H RF emissions results

Mode	Option	Test configuration	Ch 512 1850.2MHz	Ch 661 1880.0MHz	Ch 810 1909.8MHz
GSM	Phone Slide Closed	Power	27.6 dBm	30.5 dBm	27.9 dBm
		E-field [V/M]	77.2	77.7	76.2
		H-field [A/m]	0.153	0.159	0.157
		Category	M3 (-5 dB)	M3 (-5 dB)	M3 (-5 dB)
Mode	Option	Test configuration	Ch 9262 1852.4MHz	Ch 9400 1880.0MHz	Ch 9538 1907.6MHz
WCDMA	Phone Slide Closed	Power	20.1 dBm	20.7 dBm	18.7 dBm
		E-field [V/M]	31.8	29.9	29.2
		H-field [A/m]	0.075	0.073	0.073
		Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

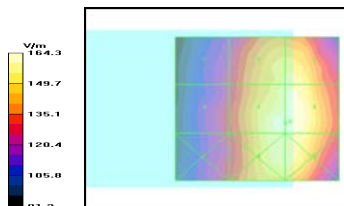
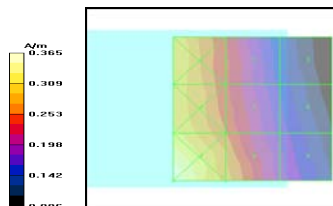
Plots of the measurement scans are shown in **Appendix B**. Excluded cells are colored orange.

APPENDIX A: SYSTEM VALIDATION SCANS

SYSTEM VALIDATION DATA 850MHZ																																																							
Date/Time: 2009-03-24 09:15:00 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1005	Date/Time: 2009-03-23 12:50:47 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1005																																																						
Communication System: CW835 Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Dipole Section	Communication System: CW835 Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section																																																						
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																																																						
E Scan - ER3DV6 - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 163.2 V/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 105.8 V/m; Power Drift = 0.020 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1</td><td>Grid 2</td><td>Grid 3</td></tr><tr><td>146.7</td><td>150.8</td><td>148.2</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 4</td><td>Grid 5</td><td>Grid 6</td></tr><tr><td>84.3</td><td>86.1</td><td>84.0</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 7</td><td>Grid 8</td><td>Grid 9</td></tr><tr><td>158.0</td><td>163.2</td><td>155.0</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr></table>	Grid 1	Grid 2	Grid 3	146.7	150.8	148.2	M4	M4	M4	Grid 4	Grid 5	Grid 6	84.3	86.1	84.0	M4	M4	M4	Grid 7	Grid 8	Grid 9	158.0	163.2	155.0	M4	M4	M4	H Scan - H3DV6 - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.456 A/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 0.484 A/m; Power Drift = 0.001 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)  <table><tr><td>Grid 1</td><td>Grid 2</td><td>Grid 3</td></tr><tr><td>0.367</td><td>0.391</td><td>0.377</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 4</td><td>Grid 5</td><td>Grid 6</td></tr><tr><td>0.429</td><td>0.456</td><td>0.437</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr><tr><td>Grid 7</td><td>Grid 8</td><td>Grid 9</td></tr><tr><td>0.382</td><td>0.404</td><td>0.386</td></tr><tr><td>M4</td><td>M4</td><td>M4</td></tr></table>	Grid 1	Grid 2	Grid 3	0.367	0.391	0.377	M4	M4	M4	Grid 4	Grid 5	Grid 6	0.429	0.456	0.437	M4	M4	M4	Grid 7	Grid 8	Grid 9	0.382	0.404	0.386	M4	M4	M4
Grid 1	Grid 2	Grid 3																																																					
146.7	150.8	148.2																																																					
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M4	M4	M4																																																					

SYSTEM VALIDATION DATA 1900MHz																			
Date/Time: 2009-03-24 09:07:08 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1004	Date/Time: 2009-03-23 13:08:16 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1004																		
Communication System: CW1880 Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m ³ Phantom section: E Dipole Section	Communication System: CW1880 Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m ³ Phantom section: H Dipole Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - ER3DV6 - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 138.7 V/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 155.9 V/m; Power Drift = 0.004 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)  <table><tr><td>Grid 1 131.1 M2</td><td>Grid 2 135.5 M2</td><td>Grid 3 133.8 M2</td></tr><tr><td>Grid 4 88.6 M3</td><td>Grid 5 91.1 M3</td><td>Grid 6 87.7 M3</td></tr><tr><td>Grid 7 132.5 M2</td><td>Grid 8 138.7 M2</td><td>Grid 9 136.6 M2</td></tr></table>	Grid 1 131.1 M2	Grid 2 135.5 M2	Grid 3 133.8 M2	Grid 4 88.6 M3	Grid 5 91.1 M3	Grid 6 87.7 M3	Grid 7 132.5 M2	Grid 8 138.7 M2	Grid 9 136.6 M2	H Scan - H3DV6 - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.465 A/m Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, 354.7 mm Reference Value = 0.491 A/m; Power Drift = -0.005 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)  <table><tr><td>Grid 1 0.400 M2</td><td>Grid 2 0.426 M2</td><td>Grid 3 0.414 M2</td></tr><tr><td>Grid 4 0.435 M2</td><td>Grid 5 0.465 M2</td><td>Grid 6 0.450 M2</td></tr><tr><td>Grid 7 0.399 M2</td><td>Grid 8 0.428 M2</td><td>Grid 9 0.414 M2</td></tr></table>	Grid 1 0.400 M2	Grid 2 0.426 M2	Grid 3 0.414 M2	Grid 4 0.435 M2	Grid 5 0.465 M2	Grid 6 0.450 M2	Grid 7 0.399 M2	Grid 8 0.428 M2	Grid 9 0.414 M2
Grid 1 131.1 M2	Grid 2 135.5 M2	Grid 3 133.8 M2																	
Grid 4 88.6 M3	Grid 5 91.1 M3	Grid 6 87.7 M3																	
Grid 7 132.5 M2	Grid 8 138.7 M2	Grid 9 136.6 M2																	
Grid 1 0.400 M2	Grid 2 0.426 M2	Grid 3 0.414 M2																	
Grid 4 0.435 M2	Grid 5 0.465 M2	Grid 6 0.450 M2																	
Grid 7 0.399 M2	Grid 8 0.428 M2	Grid 9 0.414 M2																	

APPENDIX B: MEASUREMENT SCANS

MEASUREMENT DATA GSM850, CHANNEL LOW (824.2 MHz)																			
Date/Time: 2009-03-24 10:27:51 Test Laboratory: TCC Nokia Type: RM-507; Serial: 004401/10/405349/7	Date/Time: 2009-03-23 13:53:46 Test Laboratory: TCC Nokia Type: RM-507; Serial: 004401/10/405349/7																		
Communication System: GSM850 (ER3DV6) Frequency: 824.2 MHz; Duty Cycle: 1:7.9 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: E Device Section	Communication System: GSM850 (H3DV6) Frequency: 824.2 MHz; Duty Cycle: 1:7.28 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - ER3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 164.3 V/m Probe Modulation Factor = 2.81 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 62.2 V/m; Power Drift = 0.372 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB) <table><tr><td>Grid 1 125.6 M4</td><td>Grid 2 156.9 M3</td><td>Grid 3 158.2 M3</td></tr><tr><td>Grid 4 129.6 M4</td><td>Grid 5 163.7 M3</td><td>Grid 6 164.3 M3</td></tr><tr><td>Grid 7 129.1 M4</td><td>Grid 8 159.9 M3</td><td>Grid 9 159.8 M3</td></tr></table>	Grid 1 125.6 M4	Grid 2 156.9 M3	Grid 3 158.2 M3	Grid 4 129.6 M4	Grid 5 163.7 M3	Grid 6 164.3 M3	Grid 7 129.1 M4	Grid 8 159.9 M3	Grid 9 159.8 M3	H Scan - H3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.283 A/m Probe Modulation Factor = 2.70 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.077 A/m; Power Drift = 0.497 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB) <table><tr><td>Grid 1 0.308 M4</td><td>Grid 2 0.239 M4</td><td>Grid 3 0.157 M4</td></tr><tr><td>Grid 4 0.316 M4</td><td>Grid 5 0.255 M4</td><td>Grid 6 0.174 M4</td></tr><tr><td>Grid 7 0.365 M4</td><td>Grid 8 0.283 M4</td><td>Grid 9 0.192 M4</td></tr></table>	Grid 1 0.308 M4	Grid 2 0.239 M4	Grid 3 0.157 M4	Grid 4 0.316 M4	Grid 5 0.255 M4	Grid 6 0.174 M4	Grid 7 0.365 M4	Grid 8 0.283 M4	Grid 9 0.192 M4
Grid 1 125.6 M4	Grid 2 156.9 M3	Grid 3 158.2 M3																	
Grid 4 129.6 M4	Grid 5 163.7 M3	Grid 6 164.3 M3																	
Grid 7 129.1 M4	Grid 8 159.9 M3	Grid 9 159.8 M3																	
Grid 1 0.308 M4	Grid 2 0.239 M4	Grid 3 0.157 M4																	
Grid 4 0.316 M4	Grid 5 0.255 M4	Grid 6 0.174 M4																	
Grid 7 0.365 M4	Grid 8 0.283 M4	Grid 9 0.192 M4																	

MEASUREMENT DATA GSM850, CHANNEL MIDDLE (836.6 MHz)

Date/Time: 2009-03-24 10:17:48
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 13:39:17
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

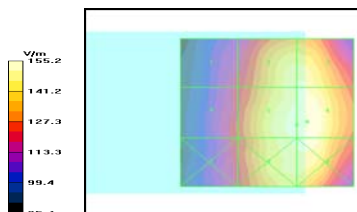
Communication System: GSM850 (ER3DV6)
Frequency: 836.6 MHz; Duty Cycle: 1:7.9
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM850 (H3DV6)
Frequency: 836.6 MHz; Duty Cycle: 1:7.28
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

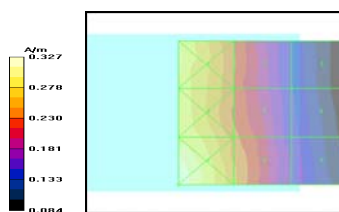
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 155.2 V/m
Probe Modulation Factor = 2.81
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 60.6 V/m; Power Drift = 0.020 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

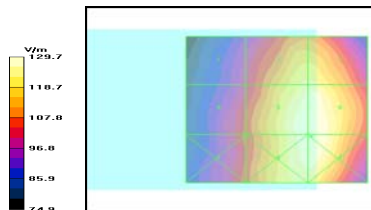
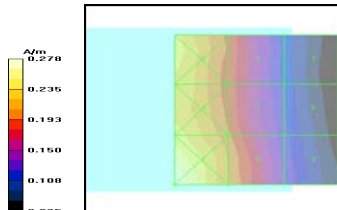


Grid 1 120.4 M4	Grid 2 150.9 M3	Grid 3 151.4 M3
Grid 4 123.9 M4	Grid 5 154.3 M3	Grid 6 155.2 M3
Grid 7 123.3 M4	Grid 8 152.7 M3	Grid 9 153.5 M3

H Scan - H3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.251 A/m
Probe Modulation Factor = 2.70
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.075 A/m; Power Drift = 0.131 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)



Grid 1 0.300 M4	Grid 2 0.232 M4	Grid 3 0.151 M4
Grid 4 0.293 M4	Grid 5 0.238 M4	Grid 6 0.159 M4
Grid 7 0.327 M4	Grid 8 0.251 M4	Grid 9 0.165 M4

MEASUREMENT DATA GSM850, CHANNEL HIGH (848.8 MHz)																			
Date/Time: 2009-03-24 10:22:51 Test Laboratory: TCC Nokia Type: RM-507; Serial: 004401/10/405349/7	Date/Time: 2009-03-23 13:48:58 Test Laboratory: TCC Nokia Type: RM-507; Serial: 004401/10/405349/7																		
Communication System: GSM850 (ER3DV6) Frequency: 848.8 MHz; Duty Cycle: 1:7.9 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m ³ Phantom section: E Device Section	Communication System: GSM850 (H3DV6) Frequency: 848.8 MHz; Duty Cycle: 1:7.28 Medium: Air; Medium Notes: - Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m ³ Phantom section: H Device Section																		
DASY4 Configuration: - Probe: ER3DV6 - SN2309 - ConvF(1, 1, 1); Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184	DASY4 Configuration: - Probe: H3DV6 - SN6143 - ; Calibrated: 2008-11-13 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn555; Calibrated: 2008-11-07 - Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: - - Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184																		
E Scan - ER3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 129.7 V/m Probe Modulation Factor = 2.81 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 50.2 V/m; Power Drift = 0.292 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)	H Scan - H3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.207 A/m Probe Modulation Factor = 2.70 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.062 A/m; Power Drift = 0.062 dB Hearing Aid Near-Field Category: M4 (AWF -5 dB)																		
 <table><tr><td>Grid 1 100.1 M4</td><td>Grid 2 123.7 M4</td><td>Grid 3 123.7 M4</td></tr><tr><td>Grid 4 105.6 M4</td><td>Grid 5 129.4 M4</td><td>Grid 6 129.7 M4</td></tr><tr><td>Grid 7 106.2 M4</td><td>Grid 8 129.4 M4</td><td>Grid 9 129.7 M4</td></tr></table>	Grid 1 100.1 M4	Grid 2 123.7 M4	Grid 3 123.7 M4	Grid 4 105.6 M4	Grid 5 129.4 M4	Grid 6 129.7 M4	Grid 7 106.2 M4	Grid 8 129.4 M4	Grid 9 129.7 M4	 <table><tr><td>Grid 1 0.242 M4</td><td>Grid 2 0.190 M4</td><td>Grid 3 0.119 M4</td></tr><tr><td>Grid 4 0.244 M4</td><td>Grid 5 0.196 M4</td><td>Grid 6 0.128 M4</td></tr><tr><td>Grid 7 0.278 M4</td><td>Grid 8 0.207 M4</td><td>Grid 9 0.136 M4</td></tr></table>	Grid 1 0.242 M4	Grid 2 0.190 M4	Grid 3 0.119 M4	Grid 4 0.244 M4	Grid 5 0.196 M4	Grid 6 0.128 M4	Grid 7 0.278 M4	Grid 8 0.207 M4	Grid 9 0.136 M4
Grid 1 100.1 M4	Grid 2 123.7 M4	Grid 3 123.7 M4																	
Grid 4 105.6 M4	Grid 5 129.4 M4	Grid 6 129.7 M4																	
Grid 7 106.2 M4	Grid 8 129.4 M4	Grid 9 129.7 M4																	
Grid 1 0.242 M4	Grid 2 0.190 M4	Grid 3 0.119 M4																	
Grid 4 0.244 M4	Grid 5 0.196 M4	Grid 6 0.128 M4																	
Grid 7 0.278 M4	Grid 8 0.207 M4	Grid 9 0.136 M4																	

MEASUREMENT DATA WCDMA850, CHANNEL LOW (826.4 MHz)

Date/Time: 2009-03-24 10:08:29
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:34:42
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

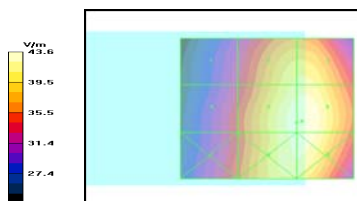
Communication System: US WCDMA850
Frequency: 826.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA850
Frequency: 826.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

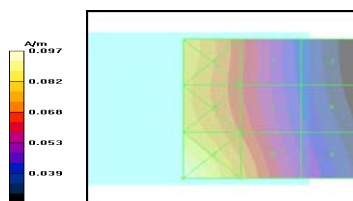
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 43.6 V/m
Probe Modulation Factor = 0.790
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 60.7 V/m; Power Drift = 0.003 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 32.7 M4	Grid 2 41.4 M4	Grid 3 41.6 M4
Grid 4 34.4 M4	Grid 5 43.4 M4	Grid 6 43.6 M4
Grid 7 35.1 M4	Grid 8 43.1 M4	Grid 9 43.2 M4

H Scan - H3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.075 A/m
Probe Modulation Factor = 0.770
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.074 A/m; Power Drift = 0.019 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.082 M4	Grid 2 0.064 M4	Grid 3 0.042 M4
Grid 4 0.083 M4	Grid 5 0.067 M4	Grid 6 0.046 M4
Grid 7 0.097 M4	Grid 8 0.075 M4	Grid 9 0.051 M4

MEASUREMENT DATA WCDMA850, CHANNEL MIDDLE (835 MHz)

Date/Time: 2009-03-24 09:57:56
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:24:17
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

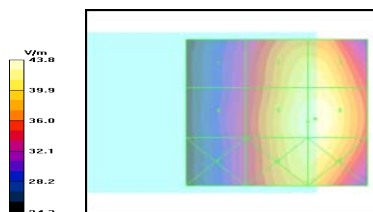
Communication System: US WCDMA850
Frequency: 835 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA850
Frequency: 835 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

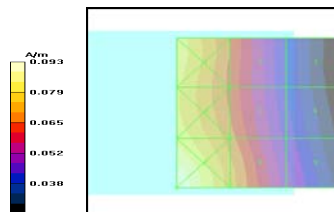
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 43.8 V/m
Probe Modulation Factor = 0.790
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 60.8 V/m; Power Drift = -0.151 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 33.0 M4	Grid 2 42.1 M4	Grid 3 42.3 M4
Grid 4 33.9 M4	Grid 5 43.6 M4	Grid 6 43.8 M4
Grid 7 33.5 M4	Grid 8 42.9 M4	Grid 9 43.1 M4

H Scan - H3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.072 A/m
Probe Modulation Factor = 0.770
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.075 A/m; Power Drift = -0.069 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.083 M4	Grid 2 0.065 M4	Grid 3 0.043 M4
Grid 4 0.083 M4	Grid 5 0.068 M4	Grid 6 0.046 M4
Grid 7 0.093 M4	Grid 8 0.072 M4	Grid 9 0.049 M4

MEASUREMENT DATA WCDMA850, CHANNEL HIGH (846.6 MHz)

Date/Time: 2009-03-24 10:03:10
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:29:44
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

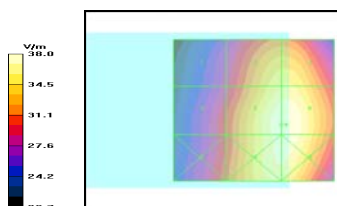
Communication System: US WCDMA850
Frequency: 846.6 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA850
Frequency: 846.6 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

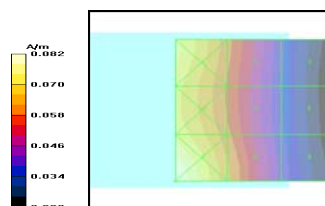
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 38.0 V/m
Probe Modulation Factor = 0.790
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 52.6 V/m; Power Drift = 0.007 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 28.5 M4	Grid 2 35.8 M4	Grid 3 35.9 M4
Grid 4 30.2 M4	Grid 5 37.9 M4	Grid 6 38.0 M4
Grid 7 30.8 M4	Grid 8 37.6 M4	Grid 9 37.7 M4

H Scan - H3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.063 A/m
Probe Modulation Factor = 0.770
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.067 A/m; Power Drift = 0.039 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.075 M4	Grid 2 0.060 M4	Grid 3 0.040 M4
Grid 4 0.073 M4	Grid 5 0.059 M4	Grid 6 0.039 M4
Grid 7 0.082 M4	Grid 8 0.063 M4	Grid 9 0.041 M4

MEASUREMENT DATA GSM1900, CHANNEL LOW (1850.2 MHz)

Date/Time: 2009-03-24 10:48:17
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:11:24
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

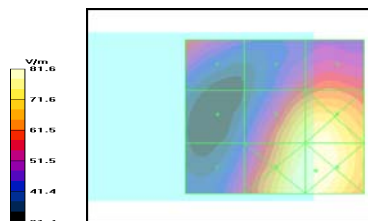
Communication System: GSM1900 (ER3DV6)
Frequency: 1850.2 MHz; Duty Cycle: 1:8.05
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM1900 (H3DV6)
Frequency: 1850.2 MHz; Duty Cycle: 1:5.01
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

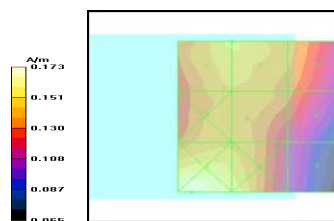
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 77.2 V/m
Probe Modulation Factor = 2.84
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 22.7 V/m; Power Drift = 0.133 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 59.7 M3	Grid 2 58.5 M3	Grid 3 62.3 M3
Grid 4 44.5 M4	Grid 5 77.2 M3	Grid 6 79.6 M3
Grid 7 54.6 M3	Grid 8 80.8 M3	Grid 9 81.6 M3

H Scan - H3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.153 A/m
Probe Modulation Factor = 2.24
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.064 A/m; Power Drift = -0.170 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 0.153 M3	Grid 2 0.153 M3	Grid 3 0.140 M4
Grid 4 0.143 M3	Grid 5 0.143 M3	Grid 6 0.133 M4
Grid 7 0.173 M3	Grid 8 0.157 M3	Grid 9 0.115 M4

MEASUREMENT DATA GSM1900, CHANNEL MIDDLE (1880 MHz)

Date/Time: 2009-03-24 10:38:48
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:01:39
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

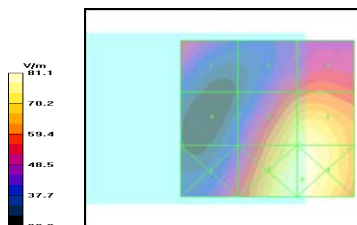
Communication System: GSM1900 (ER3DV6)
Frequency: 1880 MHz; Duty Cycle: 1:8.05
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM1900 (H3DV6)
Frequency: 1880 MHz; Duty Cycle: 1:5.01
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

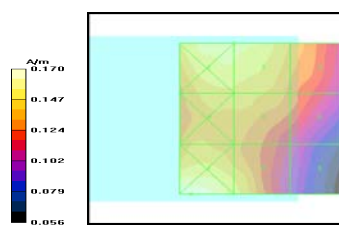
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 77.7 V/m
Probe Modulation Factor = 2.84
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 21.8 V/m; Power Drift = -0.035 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 55.8 M3	Grid 2 56.4 M3	Grid 3 59.9 M3
Grid 4 42.7 M4	Grid 5 75.4 M3	Grid 6 77.7 M3
Grid 7 55.0 M3	Grid 8 80.4 M3	Grid 9 81.1 M3

H Scan - H3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.159 A/m
Probe Modulation Factor = 2.24
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.062 A/m; Power Drift = 0.079 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 0.160 M3	Grid 2 0.159 M3	Grid 3 0.139 M4
Grid 4 0.145 M3	Grid 5 0.145 M3	Grid 6 0.129 M4
Grid 7 0.170 M3	Grid 8 0.150 M3	Grid 9 0.109 M4

MEASUREMENT DATA GSM1900, CHANNEL HIGH (1909.8 MHz)

Date/Time: 2009-03-24 10:43:32
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-23 14:06:37
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

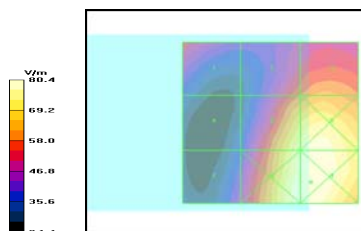
Communication System: GSM1900 (ER3DV6)
Frequency: 1909.8 MHz; Duty Cycle: 1:8.05
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: GSM1900 (H3DV6)
Frequency: 1909.8 MHz; Duty Cycle: 1:5.01
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

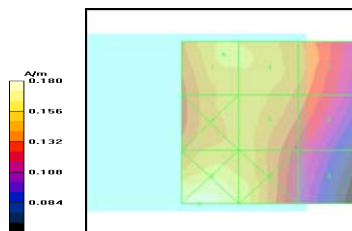
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 76.2 V/m
Probe Modulation Factor = 2.84
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 21.2 V/m; Power Drift = 0.137 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 54.0 M3	Grid 2 58.1 M3	Grid 3 63.2 M3
Grid 4 37.7 M4	Grid 5 76.2 M3	Grid 6 79.2 M3
Grid 7 46.3 M4	Grid 8 78.9 M3	Grid 9 80.4 M3

H Scan - H3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.157 A/m
Probe Modulation Factor = 2.24
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.067 A/m; Power Drift = 0.009 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)



Grid 1 0.157 M3	Grid 2 0.157 M3	Grid 3 0.144 M3
Grid 4 0.154 M3	Grid 5 0.154 M3	Grid 6 0.137 M4
Grid 7 0.180 M3	Grid 8 0.163 M3	Grid 9 0.120 M4

MEASUREMENT DATA WCDMA1900, CHANNEL LOW (1852.4MHz)

Date/Time: 2009-03-24 09:49:32
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-24 08:51:14
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

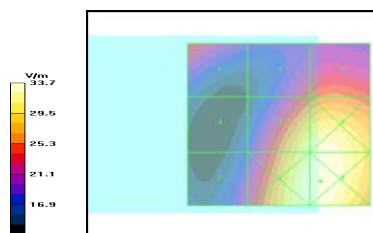
Communication System: US WCDMA1900
Frequency: 1852.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA1900
Frequency: 1852.4 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

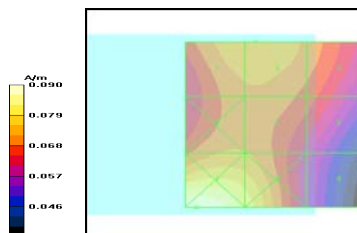
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 31.8 V/m
Probe Modulation Factor = 0.750
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 35.0 V/m; Power Drift = -0.053 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 24.4 M4	Grid 2 24.4 M4	Grid 3 25.9 M4
Grid 4 18.1 M4	Grid 5 31.8 M4	Grid 6 33.0 M4
Grid 7 21.7 M4	Grid 8 33.2 M4	Grid 9 33.7 M4

H Scan - H3DV6 - Low - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.075 A/m
Probe Modulation Factor = 0.710
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.100 A/m; Power Drift = -0.110 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.075 M4	Grid 2 0.075 M4	Grid 3 0.071 M4
Grid 4 0.072 M4	Grid 5 0.072 M4	Grid 6 0.067 M4
Grid 7 0.090 M4	Grid 8 0.082 M4	Grid 9 0.059 M4

MEASUREMENT DATA WCDMA1900, CHANNEL MIDDLE (1880MHz)

Date/Time: 2009-03-24 09:39:55
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-24 08:41:10
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

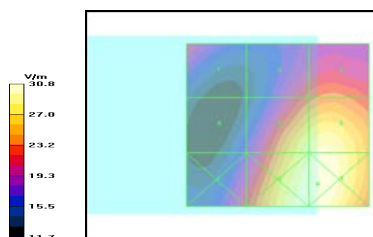
Communication System: US WCDMA1900
Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA1900
Frequency: 1880 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes: -
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

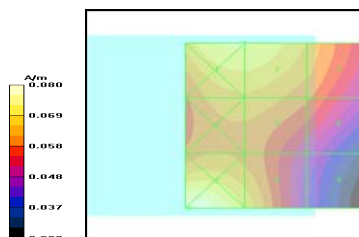
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: -
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 29.9 V/m
Probe Modulation Factor = 0.750
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 32.8 V/m; Power Drift = 0.010 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 21.1 M4	Grid 2 22.6 M4	Grid 3 23.8 M4
Grid 4 17.5 M4	Grid 5 29.1 M4	Grid 6 29.9 M4
Grid 7 21.4 M4	Grid 8 30.5 M4	Grid 9 30.8 M4

H Scan - H3DV6 - Middle - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.073 A/m
Probe Modulation Factor = 0.710
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.087 A/m; Power Drift = -0.044 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.074 M4	Grid 2 0.073 M4	Grid 3 0.066 M4
Grid 4 0.065 M4	Grid 5 0.065 M4	Grid 6 0.059 M4
Grid 7 0.080 M4	Grid 8 0.068 M4	Grid 9 0.048 M4

MEASUREMENT DATA WCDMA1900, CHANNEL HIGH (1907.6MHz)

Date/Time: 2009-03-24 09:44:44
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

Date/Time: 2009-03-24 08:46:03
Test Laboratory: TCC Nokia
Type: RM-507; Serial: 004401/10/405349/7

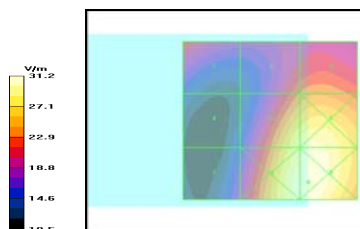
Communication System: US WCDMA1900
Frequency: 1907.6 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes:
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
Phantom section: E Device Section

Communication System: US WCDMA1900
Frequency: 1907.6 MHz; Duty Cycle: 1:1
Medium: Air; Medium Notes:
Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2309
- ConvF(1, 1, 1); Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial:
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW:
SEMCAD, V1.8 Build 184

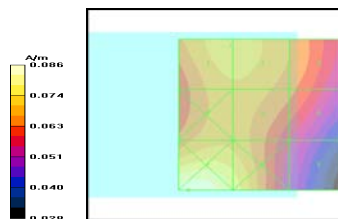
DASY4 Configuration:
- Probe: H3DV6 - SN6143
- ; Calibrated: 2008-11-13
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn555; Calibrated: 2008-11-07
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial:
- Measurement SW: DASY4, V4.7 Build 55; Postprocessing SW:
SEMCAD, V1.8 Build 184

E Scan - ER3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 29.2 V/m
Probe Modulation Factor = 0.750
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 31.5 V/m; Power Drift = -0.053 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 21.7 M4	Grid 2 23.0 M4	Grid 3 24.1 M4
Grid 4 15.4 M4	Grid 5 29.2 M4	Grid 6 30.2 M4
Grid 7 18.4 M4	Grid 8 30.7 M4	Grid 9 31.2 M4

H Scan - H3DV6 - High - Measurement Distance, Sensor Center to the Device = 15mm/Hearing Aid Compatibility Test (101x101x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.073 A/m
Probe Modulation Factor = 0.710
Device Reference Point: 0.000, 0.000, 353.7 mm
Reference Value = 0.097 A/m; Power Drift = 0.025 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)



Grid 1 0.073 M4	Grid 2 0.073 M4	Grid 3 0.067 M4
Grid 4 0.070 M4	Grid 5 0.070 M4	Grid 6 0.064 M4
Grid 7 0.086 M4	Grid 8 0.077 M4	Grid 9 0.056 M4

APPENDIX C: RELEVANT PAGES FROM PROBE CALIBRATION REPORT(S)



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client Nokia Salo TCC

Certificate No: ER3-2309_Nov08

CALIBRATION CERTIFICATE

Object ER3DV6 - SN:2309

Calibration procedure(s) QA CAL-02.v5
Calibration procedure for E-field probes optimized for close near field
evaluations in air

Calibration date: November 13, 2008

Condition of the calibrated item In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-08 (No. 217-00788)	Apr-09
Power sensor E4412A	MY41495277	1-Apr-08 (No. 217-00788)	Apr-09
Power sensor E4412A	MY41498087	1-Apr-08 (No. 217-00788)	Apr-09
Reference 3 dB Attenuator	SN: S5054 (3c)	1-Jul-08 (No. 217-00865)	Jul-09
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-08 (No. 217-00787)	Apr-09
Reference 30 dB Attenuator	SN: S5129 (30b)	1-Jul-08 (No. 217-00866)	Jul-09
Reference Probe ER3DV6	SN: 2328	1-Oct-08 (No. ER3-2328_Oct08)	Oct-09
DAE4	SN: 789	5-Dec-07 (No. DAE4-789_Dec07)	Dec-08

Secondary Standards	D #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642L01700	4-Aug-99 (in house check Oct-07)	In house check Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Katja Pokovic	Technical Manager	
Approved by:	Niels Kuster	Quality Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client Nokia Salo TCC

Certificate No: H3-6143_Nov08

CALIBRATION CERTIFICATE

Object H3DV6 - SN:6143

Calibration procedure(s) QA CAL-03.v5
Calibration procedure for H-field probes optimized for close near field
evaluations in air

Calibration date: November 13, 2008

Condition of the calibrated item In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-08 (No. 217-00788)	Apr-09
Power sensor E4412A	MY41495277	1-Apr-08 (No. 217-00788)	Apr-09
Power sensor E4412A	MY41498087	1-Apr-08 (No. 217-00788)	Apr-09
Reference 3 dB Attenuator	SN: S5054 (3c)	1-Jul-08 (No. 217-00865)	Jul-09
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-08 (No. 217-00787)	Apr-09
Reference 30 dB Attenuator	SN: S5129 (30b)	1-Jul-08 (No. 217-00866)	Jul-09
Reference Probe H3DV6	SN: 6182	1-Oct-08 (No. H3-6182_Oct08)	Oct-09
DAE4	SN: 789	5-Dec-07 (No. DAE4-789_Dec07)	Dec-08
Secondary Standards	D #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	JS3642U01700	4-Aug-99 (in house check Oct-07)	In house check: Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Katja Pokovic	Technical Manager	
Approved by:	Niels Kuster	Quality Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

APPENDIX D: RELEVANT PAGES FROM DIPOLE VALIDATION KIT REPORT(S)



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **Nokia Salo TCC**

Certificate No: **CD835V3-1005_Nov08**

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1005
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	November 11, 2008
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI)
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	31-Dec-07 (No. ER3-2336_Dec07)	Dec-08
Probe H3DV6	SN: 6065	31-Dec-07 (No. H3-6065_-Dec07)	Dec-08
DAE4	SN: 781	03-Oct-08 (No. DAE4-781_Oct08)	Oct-09
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter EPM-4419B	GB42420191	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482A	US37295597	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482H	3318A09450	08-Jan-02 (in house check Oct-07)	In house check: Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	03-Nov-04 (in house check Oct-07)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

3.3.2 DASY4 H-field result

Date/Time: 11.11.2008 08:45:34

Test Laboratory: SPEAG Lab 2

H_CD835_1005_081111

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1005

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.441 A/m

Probe Modulation Factor = 1.00

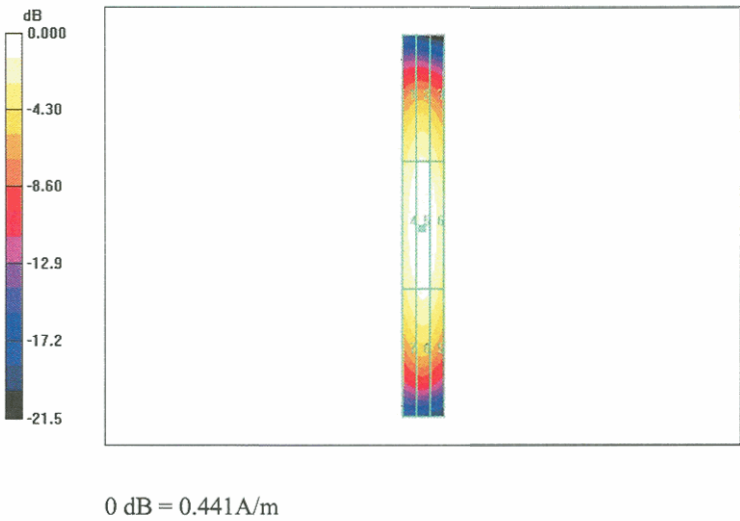
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.467 A/m; Power Drift = 0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.370 M4	Grid 2 0.385 M4	Grid 3 0.358 M4
Grid 4 0.423 M4	Grid 5 0.441 M4	Grid 6 0.412 M4
Grid 7 0.376 M4	Grid 8 0.394 M4	Grid 9 0.368 M4



Test Laboratory: SPEAG Lab 2

E_CD835_1005_081111

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1005

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

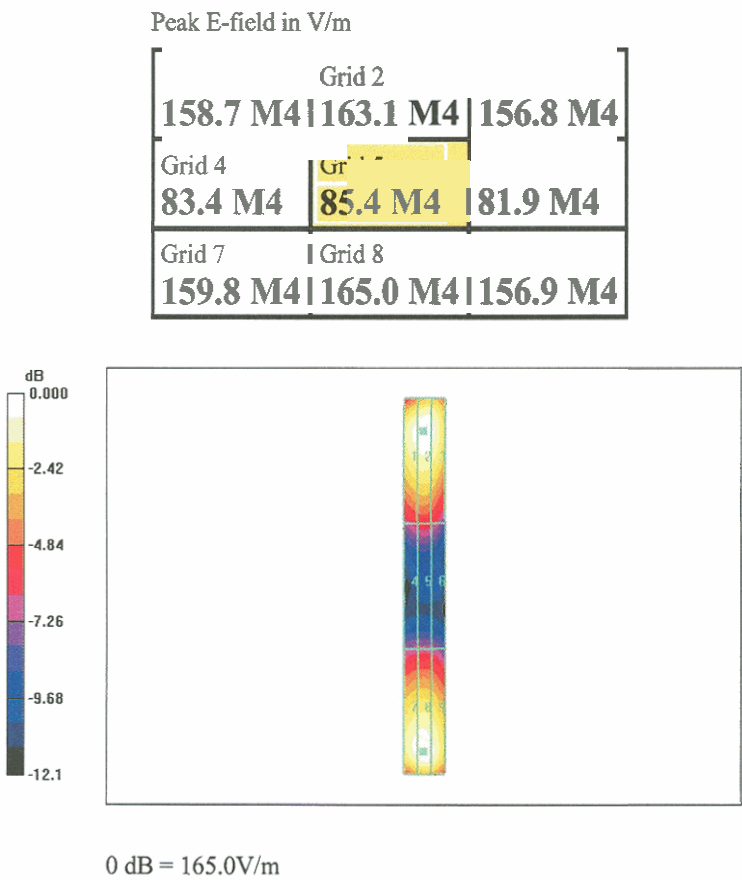
Maximum value of peak Total field = 165.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 107.1 V/m; Power Drift = -0.020 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)





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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **Nokia Salo TCC**

Certificate No: **CD1880V3-1004_Nov08**

CALIBRATION CERTIFICATE

Object	CD1880V3 - SN: 1004
Calibration procedure(s)	QA CAL-20.v4 Calibration procedure for dipoles in air
Calibration date:	November 11, 2008
Condition of the calibrated item	In Tolerance

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8481A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	31-Dec-07 (No. ER3-2336_Dec07)	Dec-08
Probe H3DV6	SN: 6065	31-Dec-07 (No. H3-6065_-Dec07)	Dec-08
DAE4	SN 781	03-Oct-08 (No. DAE4-781_Oct08)	Oct-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter EPM-4419B	GB42420191	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482A	US37295597	11-May-05 (in house check Oct-07)	In house check: Oct-09
Power sensor HP 8482H	3318A09450	08-Jan-02 (in house check Oct-07)	In house check: Oct-09
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	22-Nov-04 (in house check Oct-07)	In house check: Oct-09

Calibrated by:	Name	Function	Signature
	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: November 13, 2008

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Test Laboratory: SPEAG Lab 2

H_CD1880_1004_081111

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1004

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid

Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.461 A/m

Probe Modulation Factor = 1.00

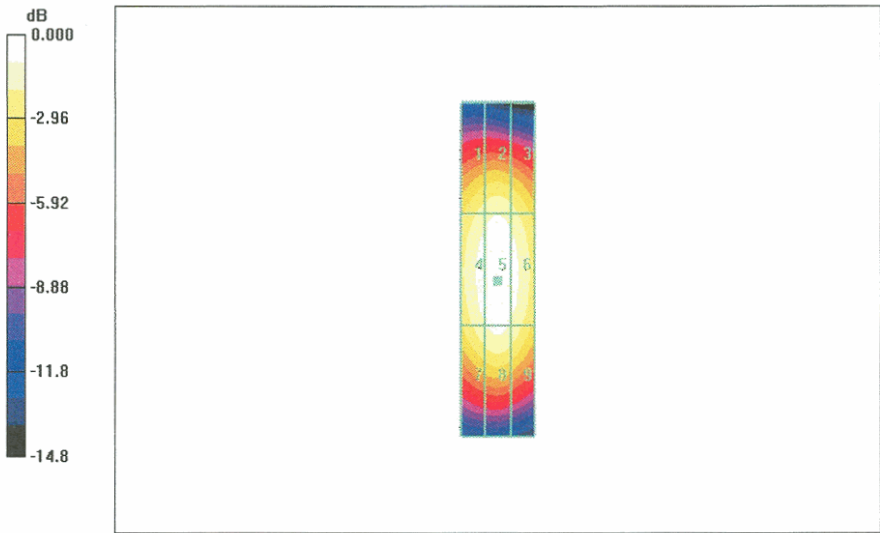
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.488 A/m; Power Drift = -0.018 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.394 M2	Grid 2 0.410 M2	Grid 3 0.390 M2
Grid 4 0.442 M2	Grid 5 0.461 M2	Grid 6 0.438 M2
Grid 7 0.409 M2	Grid 8 0.430 M2	Grid 9 0.406 M2



0 dB = 0.461A/m

3.3.2 DASY4 E-Field Result

Date/Time: 11.11.2008 12:54:31

Test Laboratory: SPEAG Lab 2

E_CD1880_1004_081111

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1004

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2007
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 03.10.2008
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 184

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 138.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 157.2 V/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

131.1 M2 136.9 M2 133.9 M2		
Grid 4 89.6 M3	5 92.1 M3	Grid 6 88.3 M3
Grid 7 133.8 M2	Grid 8 138.8 M2	Grid 9 133.2 M2

